

U.DMA6-compatible High-speed Compact Flash (CF) Card for Industrial Use CFG8B Series

Conformity to RoHS Directive

Equipped with Japan-made SLC flash memory and highly reliable CompactFlash® Card Type I with TDK GBDriver RA8

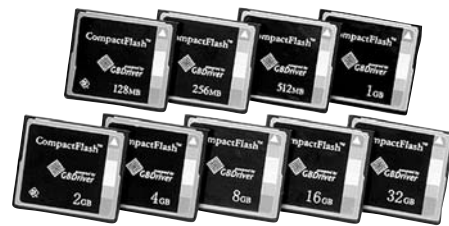
128MB, 256MB, 512MB, 1GB, 4GB, 8GB, and 16GB

TDK industrial CF (compact flash) cards: the CFG8B Series are high-speed and highly reliable CF cards equipped with TDK's own NAND-type flash memory controller IC, GBDriver RA8. The series features high-speed data access with effective reading and writing speeds of 45 MB/sec and 28 MB/sec, respectively, and has a powerful error-correcting ability that can be extended up to 15 bit/sector ECC thereby achieving high data reliability. In addition, the CFG8B Series has TDK's proprietary algorithm that minimizes bit error (read disturb error) resulting from repetition of data reading, as well as the risk of data corruption (collateral data error) due to power-off during data writing; both features help provide perfect reliability. Furthermore, the newly developed static wear leveling algorithm levels the erasing times of the flash memory in all areas of the memory; this function has considerably improved the rewriting life of the flash memory. The product also enables the erasing times of all memory blocks to be obtained as SMART (Self-Monitoring & Analysis Reporting Technology) information, thus allowing the flash life-span to be evaluated and detected quantitatively. With technical support by dedicated FAE, these CF cards are ideal for industrial use and embedment.

FEATURES

- Complies with CF+ & CompactFlash® Specification Revision 4.1.
- Equipped with TDK's proprietary developed NAND controller IC GBDriver RA8.
- Equipped with high-speed and highly-durable Japan-made SLC (Single Level Cell) NAND flash memory.
- Compatible with PIO mode0-6/Multiword DMA mode0-4/Ultra DMA mode0-6 High-speed data access with reading and writing speeds of 45 MB/sec and 28 MB/sec, respectively.*1
- Error-correcting ability: 8 or 15 bits/sec ECC (automatically selected by the flash memory's judgment).
- TDK's proprietary static wear leveling algorithm levels the erasing times of all the areas (blocks) of the equipped flash memory and considerably improves the rewriting life-span of the memory.*2
(As reference, the CFG8B CF card with a 16GB capacity can be rewritten (erased) 3.1 billion times. This is equivalent to 10-times rewriting (erasing) per second over a ten year life.)*3
- Perfectly prevents collateral errors; due to TDK's proprietary flash memory control system SSD is designed to have higher durability for system power-off.
- Supports SMART commands; histogram display of erasing times of all memory blocks enables memory life-span to be managed quantitatively.
- Equipped with a function to set the number of all sectors which allows customization of the number of logical blocks per sector allotted to the data area.
For example, decreasing the number of logical blocks can increase the possible erasing times of the flash memory, and for those applications that do not need a longer life, increasing the number of logical blocks can increase the memory capacity to the maximum. CHS parameters can also be customized.
- Supports security functions based on ATA standards. Customers can set or cancel passwords to prevent falsification of leaking of personal and confidential information.
- Dedicated FAE (Field Application Engineer) system provides speedy and reliable solutions e.g. system compatibility verification and customizing.
- Complies with RoHS Directives as a CompactFlash® Card. The components, lead terminals, etc. are all free from hazardous substances prohibited by the RoHS Directives of the EU (European Union). Therefore, the product can be safely used overseas.

- *1 Dependent on flash memory connection configuration and system environment.
- *2 The scope of static wear leveling execution can be customized. (Outside the scope of static wear leveling execution, dynamic wear leveling is executed).
- *3 This applies to a product equipped with an SLC flash memory with a structure of 4KB/page.



• CompactFlash® Card is a registered trademark of Sandisk Corporation in the United State.

• Conformity to RoHS Directive: This means that, in conformity with EU Directive 2002/95/EC, lead, cadmium, mercury, hexavalent chromium, and specific bromine-based flame retardants, PBB and PBDE, have not been used, except for exempted applications.

• All specifications are subject to change without notice.

MAIN APPLICATIONS

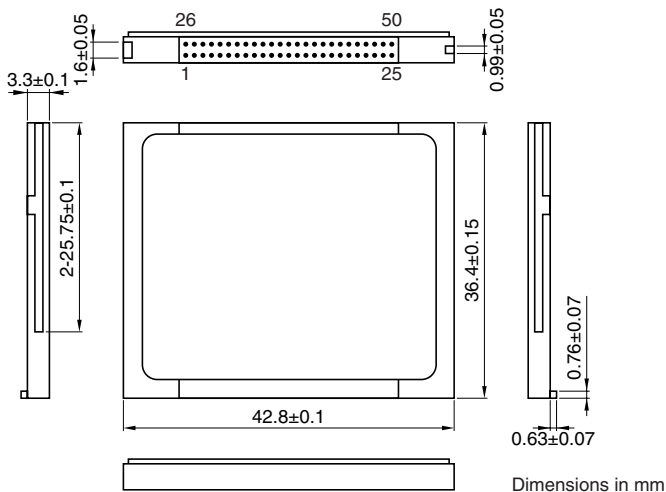
- Storing an OS, system, and user data
- POS systems, Station equipment, security systems, etc. requiring high frequency of rewriting data
- Medical equipment, logistics, machine tools, etc. requiring vibration resistance, high-speed booting, energy-saving, and downsizing
- Terminals for financial institutions, digital signage, security authentication systems, etc. requiring high data reliability and security

APPLICATION EXAMPLES

- General FA equipment: NC machine tools, sequencers, PLCs, panel computers, touch panel systems, embedded CPU boards, etc.
- Entertainment equipment for online karaoke, amusement arcades, etc.
- General social infrastructure equipment: communication and broadcasting equipment
- General crime and disaster prevention equipment: monitoring cameras
- Station equipment: automatic ticket vending and checking, and commuter pass-vending machines
- General vehicle-installed equipment: digital tachograph, data logger, drive recorder, and rear-view monitor
- General OA equipment: multifunctional printers (MFP) and business-oriented projectors, etc.
- POSs, terminals for convenience stores and kiosks, and terminals for financial institutions, ATMs, etc.
- General medical and measuring equipment: diagnostic imaging equipment, blood analysis equipment, medical PCs, and electronic medical chart systems

SHAPES AND DIMENSIONS

CompactFlash® Type I



SPECIFICATIONS

Product name	CF Card RA8 Series	SSD (GBDisk) RA8 Series
Model No.	CFG8B Series	SDG8B Series
Data capacity	128MB/256MB/512MB/1GB/2GB/4GB/8GB/16GB	1GB/2GB/4GB/8GB/16GB
Shape	CompactFlash® Type I	2.5-inch
Host IF	Ultra ATA 133	Ultra ATA 133
Transfer mode	Ultra DMA mode 0-6 Multiword DMA mode 0-4 PIO mode 0-6	Ultra DMA mode 0-6 Multiword DMA mode 0-4 PIO mode 0-6
Read(max.)	45MB/s*1	45MB/s*1
Write(max.)	28MB/s*1	28MB/s*1
Power supply voltage	3.3V±5%/5.0V±10%	5V±10%
Consumption current	145mA max.[3.3V Read/Write]*2, 5mA[Stand-by]	130mA max.[Read/Write]*2, 10mA[Stand-by]
Operating temperature	0 to +70°C[-40 to +85°C Industrial Option]	0 to +70°C[-40 to +85°C Industrial Option]
Ambient storage temperature	-25 to +85°C[-45 to +90°C Industrial Option]	-25 to +85°C[-45 to +90°C Industrial Option]
Acquired standards	CE/FCC/VCCI	CE/FCC/VCCI
Environmental specifications	RoHS compliant	RoHS compliant
Country of origin	Taiwan	Taiwan

*1 In the 2Para Interleaved mode

*2 In the 2Para mode

• All specifications are subject to change without notice.